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Substitute for Form 1449A/PTO		Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>		Application Number	Based on 09/356,376 10/724,126
		Filing Date	July 19, 1999 12/103
		First Named Inventor	Hongyong ZHANG et al.
		Group Art Unit	2871 1765
		Examiner Name	Kenneth Parker Dec
Sheet 1 of 3	Attorney Docket Number	0756-7224	

U.S. PATENT DOCUMENTS						
Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Name of Patent or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
HQ		5,849,043		Zhang et al.	12/15/98	
		4,177,372		Kotera et al.	12/04/79	
		4,370,175		Levatter	01/25/83	
		4,436,557		Wood et al.	03/13/84	
		4,826,711		Yamazaki et al.	05/02/89	
		4,979,181		Nakanose et al.	12/18/90	
		5,174,876		Buchel et al.	12/29/92	
		5,017,277		Yoshida et al.	05/21/91	
		5,205,036		Yamazaki	04/27/93	
		5,229,081		Suda	07/20/93	
		5,252,498		Yamazaki	10/12/93	
		5,272,361		Yamazaki	12/21/93	
		5,296,405		Yamazaki et al.	03/22/94	
		5,313,076		Yamazaki et al.	05/17/94	
		5,316,969		Ishida et al.	05/31/94	
		5,323,013		Kelly et al.	06/21/94	
		5,346,850		Kaschmitter et al.	09/13/94	

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		Office ¹	Number ¹	Kind Code ² (if known)				
20		JP	58-103140			06/20/83		Abst.
		JP	55-150238			11/22/80		Abst.
		JP	56-30721			03/27/81		Abst.
20		JP	62-142370			06/25/87		Abst.

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HQ		X. Tong, et al., "Effect of Si-Substrate Heating During Laser-Induced B-Doping," Appl. Phys. A Vol. 59 (March 1994) pp. 189-191.		

Examiner Signature	HQ	Date Considered	10/3/05
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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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		First Named Inventor	Hongyong ZHANG et al.
		Group Art Unit	2874 1765
		Examiner Name	Kenneth Parker DLO
Sheet 2 of 3	Attorney Docket Number	0756-7224	

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		Number	Kind Code ³ (if known)		
80		5,566,009		Yamazaki et al.	10/15/96
		5,583,369		Yamazaki et al.	12/10/96
		5,946,561		Yamazaki et al.	08/31/99
		5,938,839		Zhang	08/17/99
		5,899,547		Yamazaki et al.	05/04/99
85		4,851,363		Troxell et al.	07/25/89

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80		JP	01-259530		10/17/89	Full
		JP	50-117374		09/13/75	Concise Stmt.
		JP	62-130562		06/12/87	Abst.
		JP	64-011323		01/13/89	Abst.
		JP	02-222545		09/05/90	Full
		JP	02-224339		09/06/90	Full
		JP	02-226732		09/10/90	Abst.
		JP	01-156725		06/20/89	Full
80		JP	57-162339		10/06/82	Abst.

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80		A Slaoui, et al., "Boron Doping of Silicon by Excimer Laser Irradiation," J. Appl. Phys. A 50 (1990) pp. 479-484.	
		Kawachi et al., "Large Area Doping Process for Fabrication of Poly-Si Thin Film Transistor Using Bucket Ion Source and XeCl Excimer Laser Annealing," December 1990, pp. L2370-2372, Jpn. J. Appl. Phys. 29(12) L2370.	
80		Sameshima et al., "XeCl Excimer Laser Annealing Used to Fabricate Poly-Si TFT's," October 1989, pp. 1789-1793, Japanese J. of Appl. Phys., Vol. 28, No. 10.	

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RD		5,521,107		Yamazaki et al.	05/28/96	
		6,013,928		Yamazaki et al.	01/11/00	
		6,331,723	B1	Yamazaki et al.	12/18/01	
		6,195,139		Yamazaki et al.	02/27/01	
		4,859,908		Yoshida et al.	08/22/89	
		4,734,550		Imamura et al.	03/29/88	
		5,372,836		Imahashi et al.	12/13/94	
		5,861,337		Zhang et al.	01/19/99	
RD		6,261,856		Shinohara et al.	07/17/01	

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20		JP	54-131866		10/13/79	Abst.
		JP	01-101625		04/19/89	Abst.
20		JP	02-222154		09/04/90	Full

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20		Semiconductor World, "Excimer Laser Annealing Apparatus," pp. 196-197, October 1, 1992, (with full English translation)	

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